## NSN 5961-01-205-1910

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.260 inches

#### Terminal Length:

1.500 inches

#### **Overall Diameter:**

0.335 inches

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-5

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

#### Npn

Mounting Method:

Terminal

**Terminal Circle Diameter:** 

0.200 inches

#### Features Provided:

Hermetically sealed case and quality assurance level tx

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

3.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

150.0 static forward current transfer ratio, common-emitter

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Specification Data:

81349-mil-s-19500/349 government specification

### Shelf Life:

NI/o

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Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

